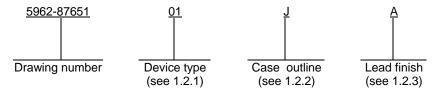
LTR A					F	REVISI	ONS										
А			DE	SCRIPTION	NC					DATE (YR-MO-DA)		·DA)	APPROVED				
	Changes in ac	cordance	with N	IOR 5962-	R026-9	94				93-11-05 M. A		M. A.	Frye				
В	Updated boiler programming changes throu	rplate. Ad requireme	ded de	evice type	s 02 ar	nd 03. F			orial		94-0)8-19			M. A. Frye		
С	Boilerplate upo		of 5 ve	ear review	ksr						06-0	9-13		Ra	Raymond Monnin		
REV SHEET																	
SHEET																	
SHEET																	
SHEET REV SHEET	S	REV		C	C	C	C	C	C	C	C	C	C				
		REV		C 1	C 2	C 3	C 4	C 5	C 6	C 7	C 8	C 9	C 10				
SHEET REV SHEET REV STATUS OF SHEETS MIC N/A		SHEI PREF Ke	ET PARED enneth	D BY S. Rice BY				5	6 EFEN	7 SE SI	8 JPPL BUS,	9 Y CE	10 NTER D 432	18-39		Js	
SHEET REV SHEET REV STATUS OF SHEETS MIC N/A STAI		SHEI PREF Ke	ET PARED enneth	1 D BY S. Rice				5	6 EFEN	7 SE SI	8 JPPL BUS,	9 Y CE	10	18-39		JS	
SHEET REV SHEET REV STATUS DF SHEETS MIC N/A STAI MICRO DRA	NDARD DCIRCUIT AWING NG IS AVAILABLE ISE BY ALL	SHEI PREF Ke CHEC D	ET PARED PARED CKED . H. Jo	D BY S. Rice BY			4 MIC	DE CRC	6 EFEN CC	SE SI DLUM http	8 UPPL BUS, o://ww	9 Y CE, OHIO vw.ds	NTER O 432 cc.dla	18-39 a.mil Y, D	990 OIGIT	 ΓAL,	
SHEET REV SHEET REV STATUS OF SHEETS MIC N/A STAI MICRO DRA THIS DRAWIN FOR US DEPAI AND AGEN	NDARD DCIRCUIT AWING	SHEI PREF Ke CHEC D	PARECENNETH CKED . H. Jo ROVEI	D BY S. Rice BY Shnson D BY A. Frye	2	3	MIC CM RE	DE CRC	EFEN CC DCIF , 1K	SE SI DLUM http	JPPL BUS, b://ww	Y CE, OHIG	NTER O 432 occ.dla	18-39 a.mil Y, C	DIGIT BLE	 ΓAL,	
SHEET REV SHEET REV STATUS OF SHEETS MIC N/A STAI MICRO DRA THIS DRAWIN FOR US DEPAR AND AGEN DEPARTMEN	NDARD DCIRCUIT AWING NG IS AVAILABLE JSE BY ALL RTMENTS NCIES OF THE	SHEI PREF Ke CHEC D APPI M DRAV	PARED enneth CKED . H. Jo ROVEI lichael	D BY S. Rice BY shnson D BY	2	3	MIC CM RE	DE CRC MOS AD ONO	OCIF , 1K ONI	SE SI DLUM http	JPPL BUS, o://ww IT, I PR MEM SIL	Y CE, OHIG	NTER O 432 cc.dla MOR RAW Y (P	Y, CIMA	DIGIT BLE	ΓAL,	

DSCC FORM 2233 APR 97

1. SCOPE

- 1.1 Scope. This drawing describes device requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A.
 - 1.2 Part or Identifying Number (PIN). The complete PIN is as shown in the following example:



1.2.1 Device type(s). The device type(s) identify the circuit function as follows:

Device type	Generic number 1/	Circuit function	Access time	
01		1K X 8-bit PROM	45	
02		1K X 8-bit PROM	45	
03		1K X 8-bit PROM	30	

1.2.2 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
J	CDIP2-T24 or GDIP1-T24	24	Dual-in-line
K	CDFP3-F24 or GDFP2-F24	24	Flat package
L	CDIP4-T24 or GDIP3-T24	24	Dual-in-line
3	CQCC1-N28	28	Square chip carrier

- 1.2.3 Lead finish. The lead finish is as specified in MIL-PRF-38535, appendix A.
- 1.3 Absolute maximum ratings. 2/

Supply voltage range to ground potential (V _{CC})	-0.5 V dc to +7.0 V dc
Lead temperature (soldering, 10 seconds)	
Thermal resistance, junction-to-case (θ_{JC})	
Junction temperature (T _J)	+150°C <u>4</u> /
Storage temperature range (T _{STG})	-65°C to +150°C
Temperature under bias	
Data retention	10 years, minimum

1.4 Recommended operating conditions.

Supply voltage range (V _{CC})	+4.5 V dc minimum to +5.5 V dc maximum
Ground voltage (GND)	0 V dc
Input high voltage range (V _{IH})	+2.0 V dc to V _{CC}
Input low voltage range (V _{IL})	-0.5 V dc to +0.8 V dc
Case operating temperature range (T _C)	-55°C to +125°C

- 1/ Generic numbers are listed on the Standardized Military Drawing Source Approval Bulletin and in MIL-HDBK-103.
- Unless otherwise specified, all voltages are referenced to ground.
 Must withstand the added P_D due to short circuit test; e.g., I_{OS}.
- 4/ Maximum junction temperature may be inceased to +175°C during burn-in and steady state life tests.

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2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standards, and handbooks</u>. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.

MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.

MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at http://assist.daps.dla.mil/quicksearch/ or http:

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item requirements shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein. Product built to this drawing that is produced by a Qualified Manufacturer Listing (QML) certified and qualified manufacturer or a manufacturer who has been granted transitional certification to MIL-PRF-38535 may be processed as QML product in accordance with the manufacturers approved program plan and qualifying activity approval in accordance with MIL-PRF-38535. This QML flow as documented in the Quality Management (QM) plan may make modifications to the requirements herein. These modifications shall not affect form, fit, or function of the device. These modifications shall not affect the PIN as described herein. A "Q" or "QML" certification mark in accordance with MIL-PRF-38535 is required to identify when the QML flow option is used.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535, appendix A and herein.
 - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.2 Truth table. The truth table shall be as specified on figure 2.
- 3.2.2.1 <u>Unprogrammed devices</u>. The truth table for unprogrammed devices for contracts involving no altered item drawing shall be as specified on figure 2. When required in groups A, B, C, or D (see 4.3), the devices shall be programmed by the manufacturer prior to test with a checkerboard pattern or equivalent (a minimum of 50 percent of the total number of bits programmed) or to any altered item drawing pattern which includes at least 25 percent of the total number of bits programmed.
 - 3.2.2.2 Programmed devices. The requirements for supplying programmed devices are not part of this drawing.
 - 3.2.3 <u>Case outlines</u>. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full case operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.

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TABLE I. Electrical performance characteristics.

		Conditions			Lim	its	
Test	Symbol	-55°C ≤ T _C ≤ +125°C 4.5 V dc ≤ V _{CC} ≤ 5.5 V dc unless otherwise specified	Group A subgroups	Device types	 Min 	 Max 	Unit
Output low voltage	VOL	$V_{IH} = 2.0 \text{ V}, V_{IL} = 0.8 \text{ V}$ $I_{OL} = 16 \text{ mA}, V_{CC} = \text{Min}$	1, 2, 3	 All		0.4	V
Output high voltage	Vон	$V_{IH} = 2.0 \text{ V}, V_{IL} = 0.8 \text{ V}$ $I_{OH} = -4.0 \text{ mA}, V_{CC} = \text{Min}$	1, 2, 3	All	2.4		V
Input high voltage 1/	 VIH 	 	 1, 2, 3 	 All 	 2.0 	 	 V
Input low voltage 1/	VIL		1, 2, 3	All		0.8	V
Input leakage current	I _{IX}	V _{CC} = Max V _{IN} = GND to 5.5 V	1, 2, 3	 All	-10	+10	μA
Output leakage current	loz	V_{CC} = Max V_{OUT} = V_{OH} and V_{OL} Output disabled	1, 2, 3	All	-10	+10	 μΑ
Output short circuit current	I _{OS}	V _{CC} = Max, V _{OUT} = GND	1, 2, 3	All	-20	-90	mA
Power supply current	Icc	V _{CC} = Max, I _{OUT} = 0 mA	1, 2, 3	All		120	mA
Input capacitance	C _{IN} <u>2</u> /	V _{IN} = 0 V, V _{CC} = 5.0 V f = 1 MHz, T _A = +25°C See 4.3.1c	4	All		10	pF
Output capacitance	C _{OUT}	V _{OUT} = 0 V, V _{CC} = 5.0 V f = 1 MHz, T _A = +25°C See 4.3.1c	4	All	 	10	pF
Functional tests		See 4.3.1e	7, 8A, 8B	All			
Address to output valid	t _{AA}	See figure 4 4/	9, 10, 11	01,02 03		45 30	ns
Chip select active to output valid	t _{ACS}		9, 10, 11	01,02 03		25 20	ns
Chip select inactive to high-Z	t _{HZCS}	See figure 4 2/ <u>4</u> / <u>5</u> /	9, 10, 11	01,02		25 20	ns

- 1/ These are absolute values with respect to device ground and all overshoots due to system or tester noise are included.
- 2/ Tested initially and after any design or process change which may affect that parameter, and therefore shall be guaranteed to the limits specified in table I.
- 3/ For test purposes, not more than one output at a time may be shorted. Short circuit test duration should not exceed thirty seconds.
- $\underline{4}$ / AC tests are performed with input rise and fall times of 5 ns or less, timing reference levels of 1.5 V, output loading of the specified I_{OL}/I_{OH} , and loads shown in figure 3.
- 5/ Transition is measured at steady-state high level -500 mV or steady-state low level +500 mV on the output from 1.5 V level on the input and the output load in figure 3

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Device types	ALL			
Case Outlines	J, K, L	3		
Terminal Number	Termina	al Symbol		
1	A ₇	NC		
2	A ₆	A ₇		
3	A ₅	A ₆		
4	A ₄	A ₅		
5	A ₃	A ₄		
6	A ₂	A ₃		
7	A ₁	A ₂		
8	A ₀	A ₁		
9	O ₀	A ₀		
10	O ₁	NC		
11	O ₂	Ο ₀		
12	GND	O ₁		
13	O ₃	O ₂		
14	O ₄	GND		
15	O ₅	NC		
16	O ₆	О3		
17	07	O ₄		
18	CS ₄	O ₅		
19	CS ₃	O ₆		
20	CS ₂	07		
21	CS ₁	NC		
22	A ₉	CS ₄		
23	A ₈	CS ₃		
24	Vcc	CS ₂		
25		CS ₁		
26		A ₉		
27		A ₈		
28		Vcc		
		· · · · · · · · · · · · · · · · · · ·		

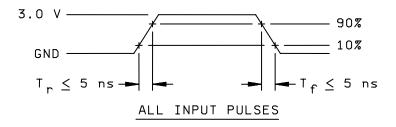
NC = no connection

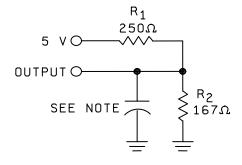
FIGURE 1. <u>Terminal connections</u>.

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	Read or output disable	CS ₄	CS ₃	CS ₂	CS ₁	Outputs
Mode	Read	VIH	VIH	VIL	VIL	Data out
	Output disable	X	Х	VIH	Х	High Z
	Output disable	X	V _{IL}	Х	Х	High Z
	Output disable	V _{IL}	Х	Х	Х	High Z
	Output disable	Х	Х	Х	VIH	High Z

FIGURE 2. Truth table.





NOTES:

- 1. C_L includes probe and jig capacitance. C_L = 30 pF for all switching characteristics except t_{HZCS} , for which C_L = 5 pF.
- 2. Tests are performed with rise and fall times of 5 ns or less.

FIGURE 3. Output load circuit and test conditions.

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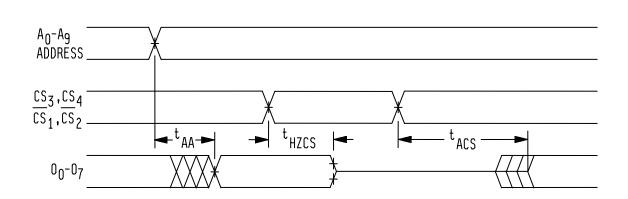


FIGURE 4. Switching waveforms.

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- 3.5 <u>Marking</u>. Marking shall be in accordance with MIL-PRF-38535, appendix A. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device.
- 3.5.1 <u>Certification/compliance mark</u>. A compliance indicator "C" shall be marked on all non-JAN devices built in compliance to MIL-PRF-38535, appendix A. The compliance indicator "C" shall be replaced with a "Q" or "QML" certification mark in accordance with MIL-PRF-38535 to identify when the QML flow option is used.
- 3.6 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-PRF-38535, appendix A and the requirements herein.
- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.
 - 3.8 Notification of change. Notification of change to DSCC-VA shall be required for any change that affects this drawing.
- 3.9 <u>Verification and review</u>. DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
- 3.10 <u>Data retention</u>. A data retention stress test shall be completed as part of the vendor's reliability monitors. This test shall be done initially and after any design or process change which may affect data retention. The methods and procedures may be vendor specific, but will guarantee the number of years listed in section 1.3 herein over the full military temperature range. The vendor's procedure shall be kept under document control and shall be made available upon request.

4. VERIFICATION

- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test. method 1015 of MIL-STD-883.
 - (1) Test condition C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
 - (2) $T_A = +125^{\circ}C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 <u>Quality conformance inspection</u>. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
 - 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - c. Subgroup 4 (C_{IN} and C_{OUT} measurement) shall be measured only for the initial test and after process or design changes which may affect capacitance. Sample size is fifteen devices with no failures and all input and output terminals tested.

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- d. Unprogrammed devices shall be tested for programmability and ac performance compliance to the requirements of Group A, subgroups 9, 10, and 11. Either of the two techniques is acceptable:
 - (1) Testing the entire lot using additional built-in test circuitry which allows the manufacturer to verify programmability and ac performance without programming the user array. If this is done, the resulting test patterns shall be verified on all devices during subgroups 9, 10, and 11, group A testing in accordance with the sampling plan specified in MIL-STD-883, method 5005.
 - (2) If such compliance cannot be tested on an unprogrammed device, a sample shall be selected to satisfy programmability requirements prior to performing subgroups 9, 10, and 11. Twelve devices shall be submitted to programming (see 3.2.2.2). If more than two devices fail to program, the lot shall be rejected. At the manufacturer's option, the sample may be increased to 24 total devices with no more than 4 total device failures allowable. Ten devices from the programmability sample shall be submitted to the requirements of group A, subgroups 9, 10, and 11. If more than two devices fail, the lot shall be rejected. At the manufacturer's option, the sample may be increased to 20 total devices with no more than 4 total device failures allowable.
- e. Subgroups 7 and 8 shall include verification of the truth table.

TABLE II. Electrical test requirements. 1/2/3/4/

MIL-STD-883 test requirements	Subgroups (in accordance with method 5005, table I)
Interim electrical parameters (method 5004)	
Final electrical test parameters (method 5004)	1*, 2, 3, 7*, 8A, 8B, 9, 10, 11
Group A test requirements (method 5005)	1, 2, 3, 4**, 7, 8A, 8B, 9, 10, 11
Groups C and D end-point electrical parameters (method 5005)	2, 3, 7, 8A, 8B

^{1/ *} Indicates PDA applies to subgroups 1 and 7.

4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test conditions, method 1005 of MIL-STD-883.
 - (1) Test condition C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
 - (2) $TA = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.
- c. Group C, subgroup 1 sample shall include devices tested in accordance with 4.3.1d.
- 4.4 <u>Programming procedures</u>. The programming procedures shall be as specified by the device manufacturer and shall be made available upon request.

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^{2/} Any or all subgroups may be combined when using high-speed testers.

^{3/ **} See 4.3.1c.

^{4/} As a minimum, subgroups 7 and 8 shall consist of verifying the data pattern.

5. PACKAGING

- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535, appendix A.
- 6. NOTES
- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.
- 6.4 <u>Record of users</u>. Military and industrial users shall inform Defense Supply Center Columbus (DSCC) when a system application requires configuration control and the applicable SMD. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0544.
- 6.5 <u>Comments</u>. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0547.
- 6.6 <u>Approved sources of supply</u>. Approved sources of supply are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

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STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 06-09-13

Approved sources of supply for SMD 5962-87651 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DSCC maintains an online database of all current sources of supply at http://www.dscc.dla.mil/Programs/Smcr/.

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962-87651013A	0C7V7 <u>3</u> /	QP7C281A-45LMB CY7C281-45LMB
5962-8765101JA	0C7V7 <u>3</u> /	QP7C282A-45DMB CY7C282-45DMB
5962-8765101KA	0C7V7 <u>3</u> /	QP7C281A-45KMB CY7C281-45KMB
5962-8765101LA	0C7V7 <u>3</u> /	QP7C281A-45DMB CY7C281-45DMB
5962-87651023A	0C7V7 0C7V7	QP7C281A-45LMB CY7C281A-45LMB
5962-8765102JA	0C7V7 0C7V7	QP7C282A-45DMB CY7C282A-45DMB
5962-8765102KA	0C7V7 0C7V7	QP7C281A-45KMB CY7C281A-45KMB
5962-8765102LA	0C7V7 0C7V7	QP7C281A-45DMB CY7C281A-45DMB
5962-87651033A	0C7V7 0C7V7	QP7C281A-30LMB CY7C281A-30LMB
5962-8765103JA	0C7V7 0C7V7	QP7C282A-30DMB CY7C282A-30DMB
5962-8765103KA	0C7V7 0C7V7	QP7C281A-30KMB CY7C281A-30KMB
5962-8765103LA	0C7V7 0C7V7	QP7C281A-30DMB CY7C281A-30DMB

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed, contact the Vendor to determine its availability.
- 2/ Caution: Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
- 3/ Not available from an approved source.

Vendor CAGEVendor namenumberand address

0C7V7 QP Semiconductor

2945 Oakmead Village Court Santa Clara, CA 95051

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.